MOSFETs Silicon N-Channel MOS (DTMOSIV)

# TK9P65W

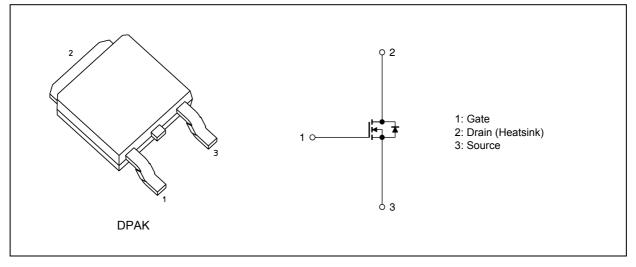
#### 1. Applications

Switching Voltage Regulators

#### 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 0.46 \Omega(typ.)$ by using Super Junction Structure : DTMOS
- (2) Easy to control Gate switching
- (3) Enhancement mode:  $V_{th}$  = 2.5 to 3.5 V( $V_{DS}$  = 10 V,  $I_D$  = 0.35 mA)

#### 3. Packaging and Internal Circuit



#### 4. Absolute Maximum Ratings (Note) ( $T_a = 25 \degree$ C unless otherwise specified)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	650	V
Gate-source voltage		V <sub>GSS</sub>	±30	
Drain current (DC)	(Note 1)	I <sub>D</sub>	9.3	Α
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	37.2	]
Power dissipation (	T <sub>c</sub> = 25 °C)	PD	80	W
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	116	mJ
Avalanche current		I <sub>AR</sub>	2.4	A
Reverse drain current (DC)	(Note 1)	I <sub>DR</sub>	9.3	]
Reverse drain current (pulsed)	(Note 1)	I <sub>DRP</sub>	37.2	1
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	]

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production

2014-09

#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance		1.57	°C/W

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: V\_DD = 90 V, T\_ch = 25 °C (initial), L = 35.8 mH, R\_G = 25  $\Omega$ , I<sub>AR</sub> = 2.4 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

#### 6. Electrical Characteristics

#### 6.1. Static Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±30 V, $V_{DS}$ = 0 V	_	_	±1	μA
Drain cut-off current	I <sub>DSS</sub>	$V_{DS}$ = 650 V, $V_{GS}$ = 0 V	_	_	10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	650	_	_	V
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.35 mA	2.5	_	3.5	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 4.6 A	_	0.46	0.56	Ω

#### 6.2. Dynamic Characteristics (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 300 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	700	_	pF
Reverse transfer capacitance	C <sub>rss</sub>		_	2.3	—	
Output capacitance	C <sub>oss</sub>		_	20	_	
Effective output capacitance	C <sub>o(er)</sub>	$V_{DS}$ = 0 to 400 V, $V_{GS}$ = 0 V	_	30	—	
Gate resistance	r <sub>g</sub>	V <sub>DS</sub> = OPEN , f = 1 MHz	_	8	—	Ω
Switching time (rise time)	t <sub>r</sub>	See Figure 6.2.1	_	16	_	ns
Switching time (turn-on time)	t <sub>on</sub>		_	40	_	
Switching time (fall time)	t <sub>f</sub>	]	_	5	_	
Switching time (turn-off time)	t <sub>off</sub>	]		70	_	
MOSFET dv/dt ruggedness	dv/dt	V <sub>DD</sub> = 0 to 400 V, I <sub>D</sub> = 4.6 A	50	_	_	V/ns

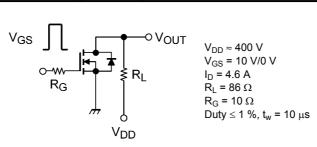


Fig. 6.2.1 Switching Time Test Circuit

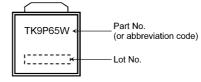
#### 6.3. Gate Charge Characteristics ( $T_a = 25 \,^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 400 \text{ V}, \text{ V}_{GS}$ = 10 V, I <sub>D</sub> = 9.3 A		20	_	nC
Gate-source charge 1	Q <sub>gs1</sub>		_	4.5	_	
Gate-drain charge	Q <sub>gd</sub>			8	_	

#### 6.4. Source-Drain Characteristics ( $T_a = 25$ °C unless otherwise specified)

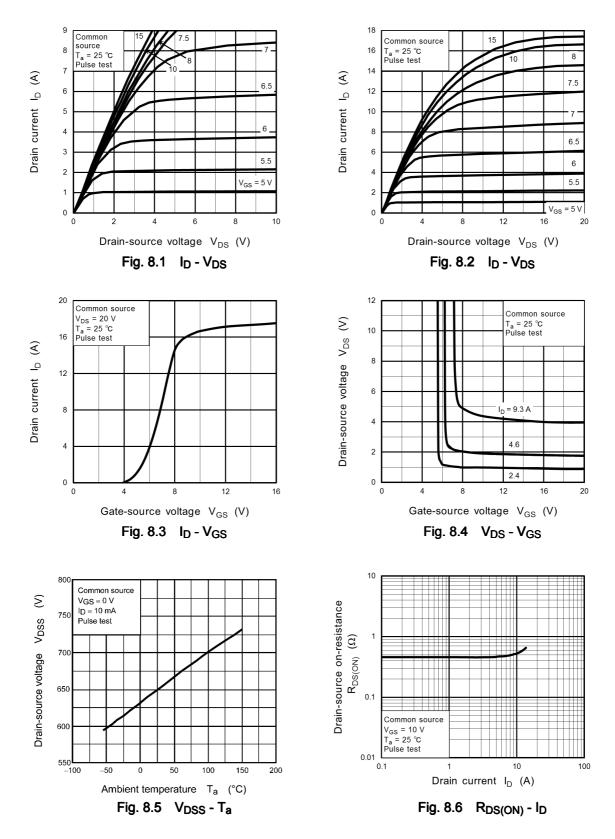
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V <sub>DSF</sub>	I <sub>DR</sub> = 9.3 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time	t <sub>rr</sub>	I <sub>DR</sub> = 4.6 A, V <sub>GS</sub> = 0 V	_	200	_	ns
Reverse recovery charge	Q <sub>rr</sub>	-dI <sub>DR</sub> /dt = 100 A/μs	_	2.2	_	μC
Peak reverse recovery current	I <sub>rr</sub>		_	19	_	А
Diode dv/dt ruggedness	dv/dt	I <sub>DR</sub> = 4.6 A, V <sub>GS</sub> = 0 V, V <sub>DD</sub> = 400 V	15			V/ns

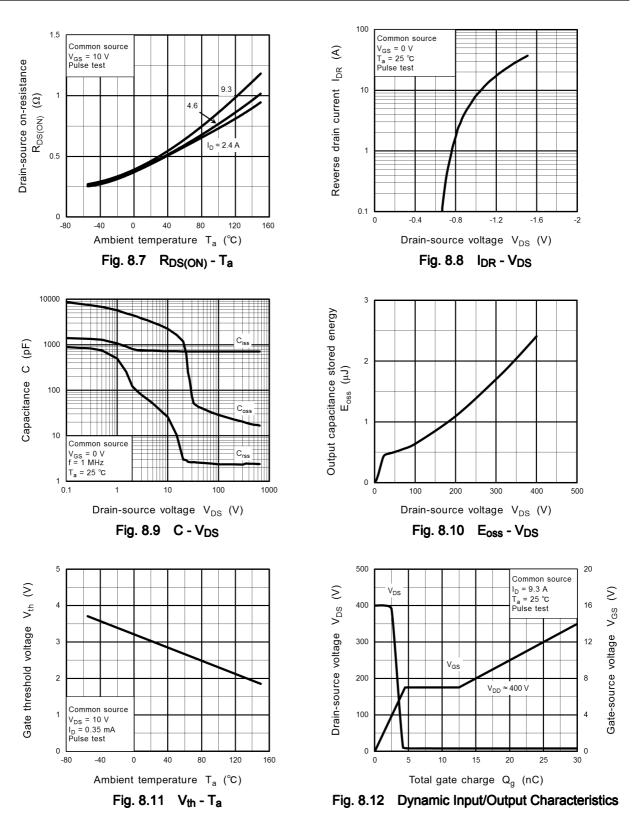
### 7. Marking





#### 8. Characteristics Curves (Note)





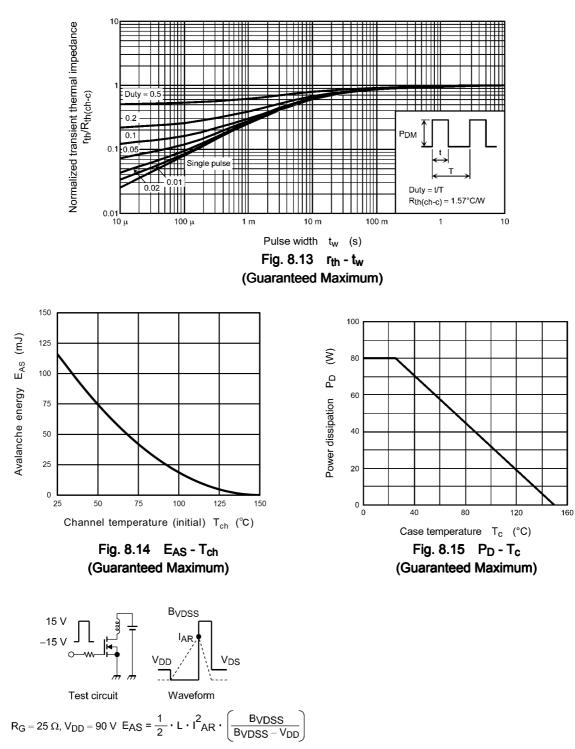
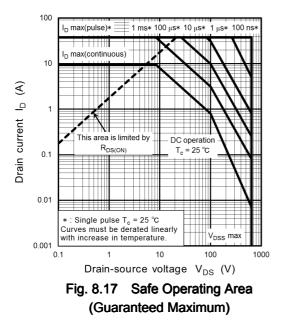


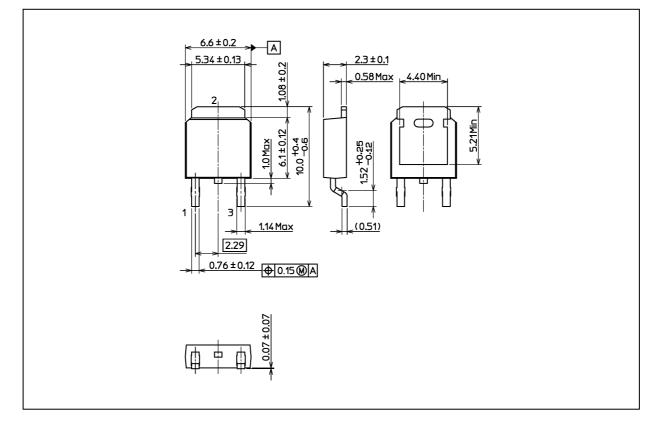
Fig. 8.16 Test Circuit/Waveform



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

#### Package Dimensions

Unit: mm



#### Weight: 0.36 g (typ.)

	Package Name(s)	
TOSHIBA: 2-7K1S		
Nickname: DPAK		

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